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RF Power Transmission for Self-sustaining Miniaturized IoT Devices

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Abstract—Radio Frequency (RF) wireless power transfer is a promising technology that has the potential to constantly power small Internet of Things (IoT) devices, enabling even battery-less systems and reducing their maintenance requirements. However, to achieve this ambitious goal, carefully designed RF energy harvesting (EH) systems are needed to minimize the conversion losses and the conversion efficiency of the limited power. For intelligent internet of things sensors and devices, which often have non-constant power requirements, an additional power management stage with energy storage is needed to temporarily provide a higher power output than the power being harvested. This paper proposes an RF wireless power energy conversion system for miniaturized IoT composed of an impedance matching network, a rectifier, and power management with energy storage. The proposed sub-system has been experimentally validated and achieved an overall power conversion efficiency (PCE) of over 30% for an input power of $-10\,\text{dBm}$ and a peak efficiency of 57% at $3\,\text{dBm}$.

Index Terms—Wireless energy transfer, RF energy harvesting, battery-less devices, self-sustaining sensors.

I. INTRODUCTION

Wireless power transfer (WPT) is an emerging technology set to supply wireless devices in the future generation of self-sustaining and battery-free Internet of Things (IoT) and wireless sensor networks (WSN) [1]. RF transmission is widely used for wireless data transfer and wireless communications. Additionally, RF waves can also carry energy together with information. Due to the recent improvement in power consumption of electronics, leading to miniaturization and reduction of power consumption of IoT devices, WPT is increasingly emerging as a potential and feasible solution as power supply technology for them [2]–[4].

Wireless power transfer has several advantages over environmental energy harvesting for the supply of IoT devices [1]. The main advantage is the controllable nature of wireless power transfer versus the unpredictable nature of environmental energy harvesting [5]. In fact, instead of harvesting energy for environmental sources, WPT technology is designed to exploit a stable and controllable wireless power supply by deploying a dedicated power transmitter that periodically or continuously sends energy [6]. Moreover, RF WPT allows long-distance energy delivery to a multitude of IoT nodes and enables a small form factor at the receiver with compact receiving antennas, especially when compared to other technologies such as inductive coupling or magnetic resonance. For these reasons, the interest for RF WPT has increased in research and industry in recent years [5], [7].

The vision for this emerging technology is to permanently power low-power devices, eliminating the need for batteries or increasing their lifespans and reducing maintenance without loss of performance [8]. This can be especially attractive in situations where a periodical change of batteries is difficult or not desired. For these reasons, powering the sensors through wireless power sources provides an effective alternative to other energy harvesting solutions such as solar, thermal, or vibration [9].

WPT is mainly divided into near- and far-field WPT depending on the spatial range of the transfer. Near-field inductive WPT is used to wirelessly power many commercially available near-field communication (NFC) devices such as credit cards and smartphones and is widely adopted [10]. However, its range is limited to few centimeters, due to the mainly inductive transfer of energy and data in the near-field. On the contrary, far-field WPT is based on sending and receiving electromagnetic (EM) waves using dipoles, which allows for power transmission at longer ranges of over 1 meter [11]. This makes far-field WPT more flexible and particularly suitable for power multi-casting, allowing the transmitter/receiver to move around, even in Non-Line-of-Sight (NLoS) environments [12]. Support of longer ranges is crucial to supply energy to IoT devices in a wide range of applications [11]. As a result, there has been a fair amount of research dedicated to the design of dedicated WPT transmitters for these sensor systems [2], [5], [11]. Despite this, far-field RF-WPT over longer ranges is still very challenging. One of the major challenges is the efficient transformation of the input EM power levels smaller than $-10\,\text{dBm}$, to the voltage and current demands of the load [13]. This is exacerbated by the need to use a miniaturized antenna and compact designs for small and unobtrusive IoT devices [14].

RF WPT is also increasing its popularity due to the availability of novel commercial products. For instance, Powercast allows power transfer up to 200 mW using a single narrow-band sub-GHz channel over several meters. Having power available at this range, combined with the possibility to supply several receivers from a single transmitter, makes RF WPT a promising power source for low-power IoT devices [2]. However, it must be taken into account that the effective power available at the IoT nodes is strongly affected by the distance, antenna size, RF matching, and rectification efficiency, and will therefore be orders of magnitude below the transmitted power of 200 mW. Therefore, to efficiently extract power from EM waves, a carefully designed RF EH system is of utmost
This paper presents the electronic blocks of an energy-efficient RF WPT sub-system for miniaturized IoT and focuses on critical design considerations for each part. The design and evaluation of an optimized RF power rectifier and matching circuit for 915 MHz for input power levels ranging from $-12$ dBm to $9$ dBm is presented. Experimental results demonstrate that the optimized design increases the conversion efficiency by up to 20% compared to off-the-shelf circuitry. Finally, the proposed sub-system, but also other commercially available RF rectifiers and power management systems are exploited to maximize the PCE. Experimental results show that it is possible to achieve an overall PCE of over 30% for an input power of $-10$ dBm which is above the state of the art for such systems.

II. ARCHITECTURE

The goal of a WPT sub-system is to extract power from electromagnetic waves received by the antenna as efficiently as possible to achieve power transfer over longer distances. Eventually, the captured electromagnetic energy is converted into a usable direct current (DC) voltage. To achieve this, each of the three main blocks of the EH system (ref. Fig. 1 (a)), impedance matching network, rectifier, and power management with energy storage requires a carefully considered design.

A. Impedance Matching Network

To achieve maximal power transfer between the source (antenna) and the load (rectifier), a carefully designed impedance matching network (IMN) is essential. By transforming the low impedance of the antenna to the system impedance, power reflections can be mitigated. Choosing discrete components with a high-quality factor minimizes power dissipation and further improves the IMN’s conversion efficiency [6].

B. Rectifier

When designing a high efficient RF-to-DC rectifier, selecting appropriate diodes is one of the most important factors since they are the main source of loss and their characteristic determines the overall performance of the rectifier. Zero-bias Schottky diodes provide very low threshold voltage and junction capacitance in comparison to common diodes, making them well-suited for RF rectifiers and allowing efficient operation [6].

C. Power Management with Energy Storage

After rectification, the harvested RF power is available as DC power and can be already used to drive a load. However, if the load’s power needs cannot be guaranteed at all times, which is especially true for miniaturized IoT devices, power management with energy storage is needed [8]. By applying strict power-saving techniques to the IoT devices, the system can still achieve self-sustainability [15].

<table>
<thead>
<tr>
<th>Designator</th>
<th>Series</th>
<th>Value</th>
</tr>
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<tbody>
<tr>
<td>C1</td>
<td>GJM1555</td>
<td>33 pF</td>
</tr>
<tr>
<td>C2</td>
<td>GQM1875</td>
<td>2.2 pF</td>
</tr>
<tr>
<td>C3</td>
<td>GJM1555</td>
<td>2.4 pF</td>
</tr>
<tr>
<td>L1</td>
<td>LQW18AN</td>
<td>50 nH</td>
</tr>
<tr>
<td>D1</td>
<td>-</td>
<td>BAT15-04W</td>
</tr>
</tbody>
</table>

The proposed WPT sub-system, illustrated in Fig. 1 (b), is optimized for a single narrow-band RF power transmitter with a center frequency of 915 MHz and is realized using off-the-shelf components. High-Q capacitors and inductors of the series GJM1555 and LQW18AN keep the conversion losses at a minimum. C1 is a DC block to allow the rectifying circuits’ DC bias to settle at mid-rail voltage. C2 and L1, together with the diode capacitances, build a single band matching network in π-configuration. The rectifier structure itself is based on a voltage doubler using BAT15-04W zero-bias RF Schottky diodes for efficient RF-to-DC conversion.

High-quality RF matching requires a well-defined printed circuit board (PCB) stackup. Thus, the proposed circuit has been realized on a 2-layer PCB using RO4003c as the core dielectric with a thickness of 0.813 mm. RO4003C provides a low and controlled dielectric constant of 3.38 over a wide frequency range and a dissipation factor of 0.0027 at 10 GHz, making it well suited for power-sensitive high-frequency designs.

For power management and energy storage, the E-PEAS AEM30940 energy management circuit has been selected [ref. Fig.1 (a)]. It can start operating with empty storage elements. Since the circuit is not a battery, power from input voltages as low as 380 mV and an input power of 3 μW. Once active, power from input voltages as low as 50 mV can be converted and temporarily stored in a capacitor before generating a constant output voltage level with the internal buck converter and low drop out (LDO) regulator.
III. EXPERIMENTAL RESULTS

To evaluate the performance of the proposed sub-system it has been tuned for 915 MHz which is a commonly used carrier frequency for WPT [2], [7]. The individual functional blocks have been evaluated in terms of functionality and efficiency. Aside from the proposed narrow-band rectification circuit of section II, measurements are conducted on the e-peas AEM30940 evaluation board to facilitate reproducibility.

The evaluation of the matching and rectifier characteristics, including an optimal maximal power point configuration analysis, is given in subsection III-A. Subsection III-B evaluates the end-to-end harvesting efficiency of the e-peas harvesting integrated circuits (IC) when combined with different RF frontends. Finally, subsection III-C analyzes the cold-start sequence of the harvesting IC for low input power.

A. Matching Circuit and Rectifier

Ideally, RF harvesting circuits comprise a broadband antenna and non-frequency selective matching circuits, allowing them to harvest from a wide range of carrier signals and input powers. If the application, the carrier frequency, and the typical input power are known, the RF path can be matched precisely to the input impedance of the rectifying circuit.

Fig. 2 visualizes the characterization of the matching and rectification circuitry. For the evaluation, the two selectable input frontends on the AEM30940 evaluation board, e-peas HP and e-peas LP, respectively optimized for power levels above −10 dBm and below −10 dBm, are compared against the narrow band implantation of section II "custom". The circuit matching is analyzed with an HP7853 network analyzer at a constant source power of 0 dBm and a matched resistive load on the rectifier output replacing the subsequent circuitry. Fig. 2 (a) shows the S11 parameter of the three circuits for frequencies of up to 2 GHz. The high-quality factors of the selected components allow a narrow matching to the 915 MHz target frequency for the custom rectifier. In contrast, the e-peas HP circuit allows additional harvesting from the 868 MHz band.

To precisely analyze the rectification efficiency of the previously shown matching and rectifying circuits, an R&S SML03 signal generator configured to 915 MHz is connected to the circuit input. The peak output power and the corresponding maximal power point (MPP) configuration are measured with a source measurement unit (SMU) KEYSIGHT B2901A emulating an adaptive load. Fig. 2 (b) shows the resulting RF path efficiency as a function of the input power for optimally matched loads. The results suggest that for input signals higher than −5 dBm, the e-peas HP outperforms the e-peas LP configuration. In contrast, the custom implementation shows superior performance for input power levels between −12 dBm and 9 dBm with up to 20% efficiency gain as compared to the commercial circuit’s efficiency. The corresponding MPP configuration is shown in Fig. 2 (c). The e-peas LP configuration shows a linear shift with 0.4%/dBm over the analyzed power range. The circuits designed for higher input powers are approximately stable until 4 dBm, with a significantly rising MPP ratio above. The inset visualizes the output power for a varying load at 0 dBm.

B. Wireless Power Conversion Efficiency

Correctly controlling the output voltage of the RF path is essential to efficiently supply subsequent circuitry. The circuit behavior, when combined with an EPEAS AEM30940 harvesting IC, is shown in Fig. 3 (b). For the measurement, the previously tested RF frontends have been attached to the IC’s harvesting input. To allow a measurement of the end-to-end harvesting efficiency, shown in Fig. 3 (a) an SMU configured to 3.5 V has been connected in parallel to an intermittent energy storage capacitor $C_{\text{boost}}$. This allows monitoring of the harvested current at a stable and repeatable storage configuration. The embedded maximal power point tracking (MPPT) has been configured to 50% of the open circuit voltage. The e-peas LP frontend allows energy-positive operation of the harvesting circuitry down to −15 dBm. Combined with the high power optimized frontends, the circuit reaches −16 dBm and −15 dBm for custom and e-peas HP, respectively. The custom circuit combined with the AEM30940 IC shows in-
increased harvesting efficiency for input power levels between $-11 \text{ dBm}$ and $5 \text{ dBm}$ with a peak efficiency of 57% at $3 \text{ dBm}$.

C. Cold Start

A critical feature of intermittent operation devices is the capability to power up despite totally discharged energy storage. Fig. 3 (b) shows this cold-start behavior for the AEM30940 IC connected to the RF frontend presented in section II. The IC’s overcharge protection has been configured to $V_{\text{ovch}} = 2.7 \text{ V}$ and the under-voltage lockout level to $V_{\text{ovdis}} = 2.2 \text{ V}$. The regulator output voltage is $V_{\text{lv}} = 1.2 \text{ V}$.

At $t = 0 \text{ s}$, the harvesting circuit is supplied with a 915 MHz RF input signal with a power of $-15 \text{ dBm}$. After $35 \text{ s}$, the initial wake-up phase completes as the intermittent storage capacitor $C_{\text{boost}}$ charges to the programmed maximum. The activation of the output regulator $V_{\text{lv}}$ and the corresponding inrush currents combined with the limited input power results in consecutive under-voltage lockouts until normal operation is reached after $56 \text{ s}$. Finally, after $93 \text{ s}$, $C_{\text{boost}}$ is fully charged, and the circuit operates in overcharge protection mode.

IV. CONCLUSION

The paper proposed and evaluated a WPT sub-system, composed of an impedance matching network, rectifier, and power management with energy storage, optimized to a single narrow-band channel at 915 MHz. The experimental evaluation showed an overall PCE of over 30% at an input power of $-10 \text{ dBm}$ and a peak efficiency of 57% at $3 \text{ dBm}$. In comparison to commercial solutions, the proposed RF frontend showed an increased PCE for input power levels between $-11 \text{ dBm}$ and $5 \text{ dBm}$. The commercial IC AEM30940 from EPEAS allows to temporarily provide more power than is being harvested, acting as a buffer and keeping the voltage supply constant, which is especially important for miniaturized IoT devices. Using the proposed RF frontend, the AEM30940 is able to exit cold start after $56 \text{ s}$ from an input power as low as $-15 \text{ dBm}$ and switches to normal operation.

REFERENCES